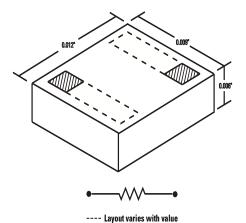
# RESISTOR

## THIN FILM CHIP RESISTOR



### **MSMR1 SERIES**

#### **MECHANICAL DATA**

SIZE SUBSTRATE RESISTOR BONDING PADS

**BACKSIDE SURFACE** 

(S)SILICON, (A)ALUMINA, (Q)QUARTZ, OR (G)GLASS NICHROME OR TANTALUM NITRIDE 15,000 Å MINIMUM GOLD

0.012" x 0.009" x 0.006" (±0.001")

10,000 Å MINIMUM: ALUMINUM OPTIONAL

BARE SUBSTRATE
GOLD BACK OPTIONAL

ELECTRICAL DATA

RESISTANCE RANGE SILICON, QUARTZ, GLASS ALUMINA TOLERANCES NICHROME  $2\Omega \ T0 \ 75 K\Omega*$   $2\Omega \ T0 \ 15 K\Omega$   $0.01\% \ T0 \ 10\%$  (Value Dependent)

TANTALUM NITRIDE  $2\Omega$  TO  $75K\Omega*$   $2\Omega$  TO  $15K\Omega$  0.01% TO 10% (Value Dependent)

T.C.R.

 $\pm 25$ ppm/°C STANDARD OPTIONAL TO  $\pm 5$ ppm/°C (S, Q, G)

±150ppm/°C STANDARD
OPTIONAL TO ±10ppm/°C (S, Q, G)
OPTIONAL TO ±25ppm/°C (A)

#### **SERIES DATA**

**CURRENT NOISE** 

DIELECTRIC BREAKDOWN
INSULATION RESISTANCE
OPERATING VOLTAGE
POWER RATING
SHORT TERM OVERLOAD
HIGH TEMP EXPOSURE
THERMAL SHOCK
MOISTURE RESISTANCE
STABILITY
OPERATING TEMP RANGE

STRAY DISTRIBUTED
CAPACITANCE
SILICON
ALUMINA

QUARTZ

2pF 0.06pF 0.02pF

101 $\Omega$  TO 250K $\Omega$ : -40dB  $\leq$  100 $\Omega$ ,  $\geq$  250K $\Omega$ : -30dB

400 V MIN.\* 10<sup>12</sup>Ω MIN. 100 V MAX.

50 mW (70°C DERATED LINEARLY TO 150°C)  $P = \sqrt{(E^*R)}$  5X RATED POWER, 25°C, 5 SEC.,  $\pm$ 0.25% MAX.  $\Delta$ R/R: 0.1% MSI TYPICAL 150°C, 100 HRS.,  $\pm$ 0.25% MAX.  $\Delta$ R/R: 0.03% MSI TYPICAL MIL-STD 202, METHOD 107F,  $\pm$ 0.25% MAX.  $\Delta$ R/R: 0.1% MSI TYPICAL MIL-STD 202, METHOD 106,  $\pm$ 0.5% MAX.  $\Delta$ R/R: 0.1% MSI TYPICAL 1000 HRS., 70°C, 125mW,  $\pm$ 0.5% MAX.  $\Delta$ R/R: 0.1% MSI TYPICAL -55°C TO  $\pm$ 125°C

#### PART NUMBER DESIGNATION

MSMR1	X	X	_	XXXXX	X	_	X
SERIES	SUBSTRATE	RESISTIVE FILM		OHMIC VALUE 5-Digit	TOLERANCE S = 0.01%*		OPTION DESIGNATOR
	A = Alumina G = Glass Q = Quartz S = Silicon	N = Nichrome T = Tantalum Nitride		Number: 1st 4 Digits Are Significant With "R" As Decimal Point When Required. 5th Digit Represents Number of Zeros.	Q = 0.05%* B = 0.1% D = 0.5% F = 1% G = 2% J = 5% K = 10%	•	(If Required) A = ±50ppm/°C B = ±25ppm/°C C = ±10ppm/°C D = ±5ppm/°C E = Aluminum Bond Pads GB = Gold Backside F = ±100ppm/°C G = Gold Pads (always used when no other option is required)



20 DAVID ROAD, N. ATTLEBORO, MA 02760 508-695-0203 FAX: 508-695-6076 EXAMPLE: MSMR 1SN-50R00F-BGB = 0.012" x 0.009", Silicon Substrate, Nichrome Resistor,  $50\Omega$ ,  $\pm 1\%$  Tol.,  $\pm 25$ ppm/°C, Gold Backside.